

KSC5026

High Voltage and High Reliability

- High Speed Switching
- Wide SOA



1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	1100	V
V _{CEO}	Collector-Emitter Voltage	800	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current (DC)	1.5	А
I _{CP}	Collector Current (Pulse)	5	Α
I _B	Base Current	0.8	Α
P _C	Collector Dissipation (T _C =25°C)	40	W
T _J	Junction Temperature DataSheet4U.com	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 1 \text{mA}, I_E = 0$	1100			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5mA, I_B = 0$	800			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 1 \text{mA}, I_C = 0$	7			V
V _{CEX} (sus)	Collector-Emitter Sustaining Voltage	$I_C = 0.75A$ $I_{B1} = -I_{B2} = 0.15A$ $L = 5$ mH, Clamped	800			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 800V, I_{E} = 0$			10	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μΑ
h _{FE1}	DC Current Gain	$V_{CE} = 5V, I_{C} = 0.1A$	10		40	
h _{FE2}		$V_{CE} = 5V, I_{C} = 0.5A$	8			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 0.75A$, $I_B = 0.15A$			2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 0.75A, I_B = 0.15A$			1.5	V
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		35		pF
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.1A$		15		MHz
t _{ON}	Turn On Time	V _{CC} = 400V			0.5	μs
t _{STG}	Storage Time	$I_C = 5I_{B1} = -2.5I_{B2} = 1A$			3	μs
t _F	Fall Time	$R_L = 400\Omega$			0.3	μs

h_{FE} Classification

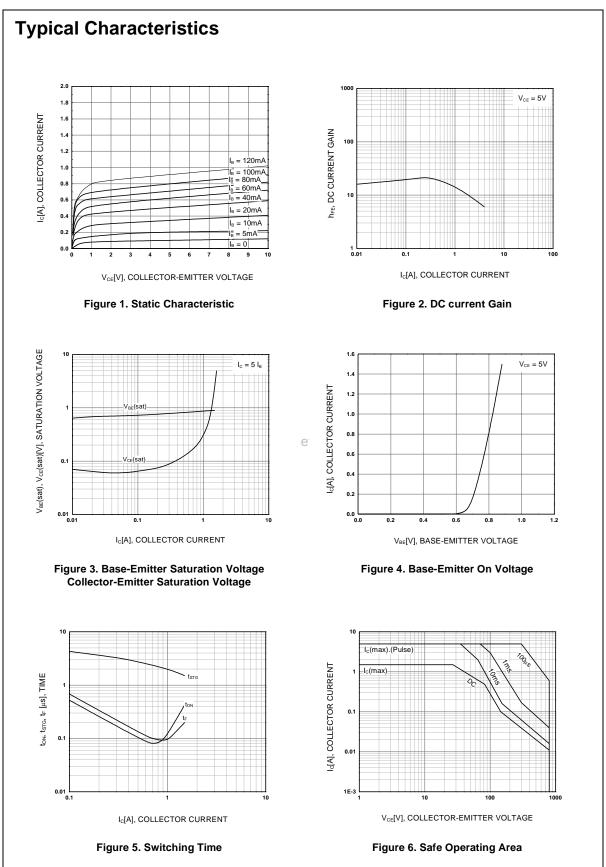
Classification	N	R	0
h _{FE1}	10 ~ 20	15 ~ 30	20 ~ 40

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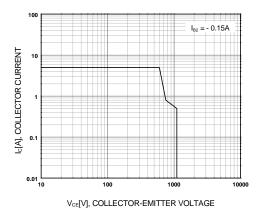
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Typical Characteristics (Continued)



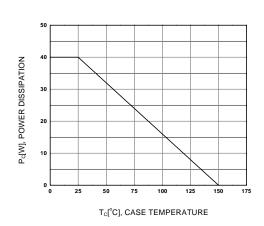


Figure 7. Reverse Bias Safe Operating Area

Figure 8. Power Derating

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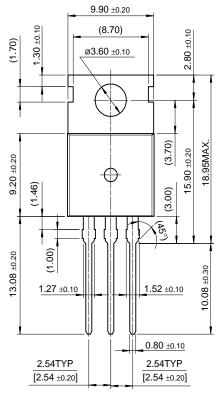
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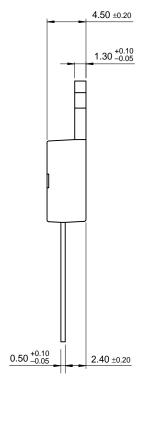
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Package Demensions

TO-220





 10.00 ± 0.20

Dimensions in Millimeters

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